SI-3025KM

1 A, Low-Dropout, 2.5 V Regulator

Designed to meet the high-current requirements in industrial and consumer applications; embedded core, memory, or logic supplies; TVs, VCRs, and office equipment, the SI-3025KM voltage regulator offers the reduced dropout voltage and low quiescent current essential for improved efficiency. This device delivers a regulated output at up to 1 A. Integrated thermal and overcurrent protection enhance overall system reliability. Devices with other output voltages are also available.

Quiescent current does not increase significantly as the dropout voltage is approached, an ideal feature in standby/resume power systems where data integrity is crucial. Regulator accuracy and excellent temperature characteristics are provided by a bandgap reference. An LS-TTL/CMOS-compatible input gives the designer complete control over power up, standby, or power down. A pnp pass element provides a dropout voltage of less than 600 mV at 1 A of load current. Low output voltages eliminate the need for expensive PWM buck converters. The low dropout voltage permits more efficient regulation before output regulation is lost.

This device is supplied in a 5-lead TO-252 style surface-mount plastic package with ground tab to provide a low-resistance path for maximum heat dissipation.

FEATURES

- 1 A Output Current at 2.5 V
- \blacksquare 0.6 V Maximum Dropout Voltage at $I_0 = 1$ A
- Fast Transient Response
- 1 µA Maximum Standby Current
- Remote Voltage Sensing
- Foldback Current Limiting
- Ground Tab for Superior Heat Dissipation
- Thermal Protection

APPLICATIONS

- TVs, VCRs, Electronic Games
- Embedded Core, Memory, or Logic Supplies
- Printers and Other Office Equipment
- Industrial Machinery
- Secondary-Side Stabilization of Multi-Output SMPS

		<i>h</i>		
		VR		
1	2	3	4	5
ENABLE	INPUT	GND	OUTPUT	SENSE
			Dv	vg. PS-022-6



ABSOLUTE MAXIMUM RATINGS

Input Voltage, V _I 17 V
Output Current, I_O 1 \mathbf{A}^*
Enable Input Voltage, V_E V_I
Junction Temperature, T_J +125°C
Storage Temperature Range, T _S 30°C to +125°C

* Output current rating is limited by input voltage, duty cycle, and ambient temperature. Under any set of conditions, do not exceed a junction temperature of +125°C.

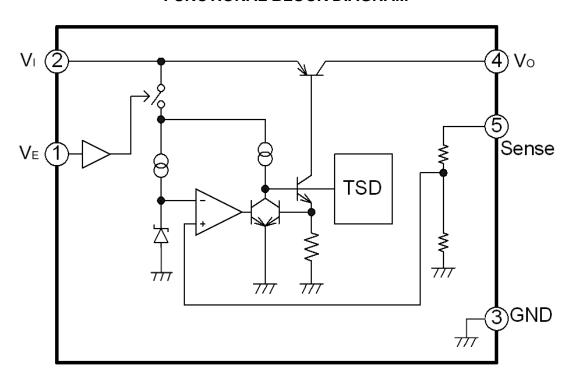
Always order by complete part number, e.g., SI-3025KM-TL where "-TL" indicates tape and reel.



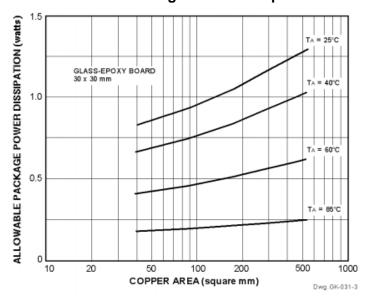




FUNCTIONAL BLOCK DIAGRAM



Allowable Package Power Dissipation



Recommended Operating Conditions

	Min	Max	Units
DC Output Current	0	1	Α
Operating Ambient Temp.	-30	+100	°C
Operating Junction Temp.	-20	+100	°C

This data sheet is based on Sanken data sheet SSJ-01993





ELECTRICAL CHARACTERISTICS at $T_A = +25$ °C, $V_E = 2$ V (unless otherwise noted).

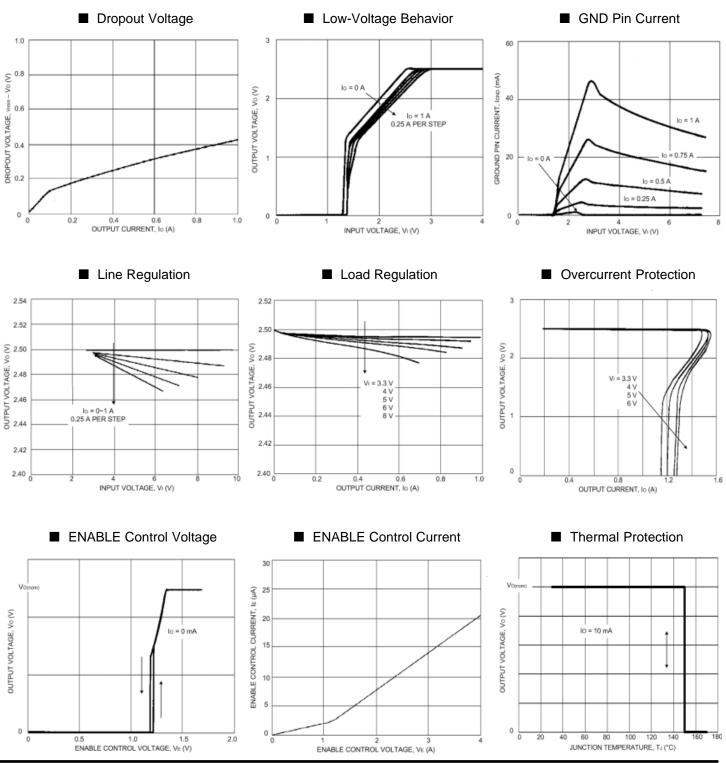
			Limits			
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Output Voltage	V _o	$V_{I} = 3.3 \text{ V}, I_{O} = 10 \text{ mA}$	2.45	2.50	2.55	V
	V _{O(off)}	$V_E = 0 V$		_	0.5	V
Output Volt. Temp. Coeff.	a _{vo}	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 100^{\circ}\text{C}$		±0.3	_	mV/°C
Output Short-Circuit Current	I _{OM}	$V_I = 3.3 \text{ V}$, See note	1.1	_	_	А
Line Regulation	$\Delta V_{O(\Delta VI)}$	$V_1 = 3.3 \text{ V} \sim 8 \text{ V}, I_0 = 10 \text{ mA}$		_	15	mV
Load Regulation	$\Delta V_{O(\Delta IO)}$	$V_1 = 3.3 \text{ V}, I_0 = 0 \text{ A} \sim 1.0 \text{ A}$		_	40	mV
Dropout Voltage	V _{Imin} - V _O	I _O = 0.5 A		_	0.4	V
		I _O = 1.0 A		_	0.6	V
Ground Terminal Current	I _{GND}	$V_{I} = 3.3 \text{ V}, I_{O} = 0 \text{ mA}, V_{E} = 2.0 \text{ V}$	_	_	350	μA
		$V_{I} = 3.3 \text{ V}, V_{E} = 0 \text{ V}$		_	1.0	μA
Enable Input Voltage	V _{EH}	Output ON	2.0	_	_	V
	V _{EL}	Output OFF		_	0.8	V
Enable Input Current	I _{EH}	$V_{E} = 2.0 \text{ V}$	_	_	40	μA
	I _{EL}	V _E = 0 V	_	0	-5.0	μA
Ripple Rejection Ratio	PSRR	$V_1 = 3.3 \text{ V}, 100 \text{ Hz} \le f \le 120 \text{ Hz}$	_	55	_	dB
Thermal Shutdown	T_J	I _O = 10 mA	135	150	_	°C

Typical values are given for circuit design information only.

Note: Output short-circuit current is at point where output voltage has decreased 5%.

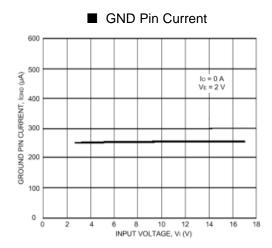
TYPICAL CHARACTERISTICS

 $(V_1 = 3.3 \text{ V}, T_A = 25^{\circ}\text{C})$



TYPICAL CHARACTERISTICS (cont.)

 $(V_1 = 3.3 \text{ V}, T_A = 25^{\circ}\text{C})$



APPLICATIONS INFORMATION

Input Capacitor (C_I , $\ge 22~\mu F$). This is necessary either when the input line includes inductance or when the wiring is long.

Output Capacitor (C_O , $\geq 22~\mu F$). This device is designed for use with a very low ESR output capacitor such as a ceramic capacitor. Output oscillation may occur with an aluminum capacitor at low temperatures.

ENABLE Input. The ENABLE (control) input features an internal pull-down resistor. Leaving this input open causes the output to turn off.

Parallel Operation. Parallel operation to increase load current is not permitted.

Increased Output Voltage. The output voltage (V_O) may be increased by inserting a resistor (R_{EXT}) between SENSE and OUTPUT. The current flowing into SENSE is typically 90 μ A $\pm 30\%$. To minimize the effect of I_{SENSE} and temperature on R_{EXT} , it is recommended that a $10~k\Omega$ resistor be added between SENSE and GND to increase the current in R_{EXT} . The value of R_{EXT} is then

$$R_{EXT} = (V_O - 2.5) \times 10^6 / 300$$

APPLICATIONS INFORMATION (cont.)

Determination of DC Input Voltage. The minimum input voltage $V_I(min)$ should be higher than the sum of the fixed output voltage and the maximum rated dropout voltage.

Overcurrent Protection. The SI-3000KM series has a built-in fold-back type overcurrent protection circuit, which limits the output current at a start-up mode. It thus cannot be used in applications that require current at the start-up mode such as:

- (1) constant-current load,
- (2) power supply with positive and negative outputs to common load (a center-tap type power supply), or
- (3) raising the output voltage by putting a diode or a resistor between the device ground and system ground.

Thermal Protection. Circuitry turns off the pass transistor when the junction temperature rises above 135°C. It is intended only to protect the device from failures due to excessive junction temperatures and should not imply that output short circuits or continuous overloads are permitted.

Heat Radiation and Reliability. The reliability of the IC is directly related to the junction temperature (T_J) in its operation. Accordingly, careful consideration should be given to heat dissipation.

The inner frame on which the integrated circuit is mounted is connected to the GND terminal (pin 3). Therefore, it is very effective for heat radiation to enlarge the copper area that is connected to the GND terminal. The graph illustrates the effect of the copper area on the junction-to-ambient thermal resistance ($R_{\rm HA}$).

The junction temperature (T_J) can be determined from either of the following equations:

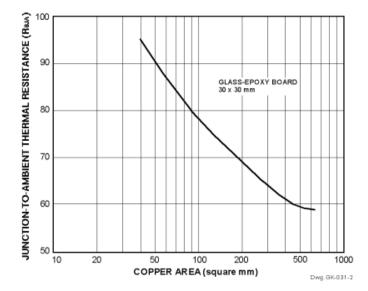
$$T_{J} = (P_{D} \times R_{\theta JA}) + T_{A}$$

or

$$T_{J} = (P_{D} \times R_{\theta JT}) + T_{T}$$

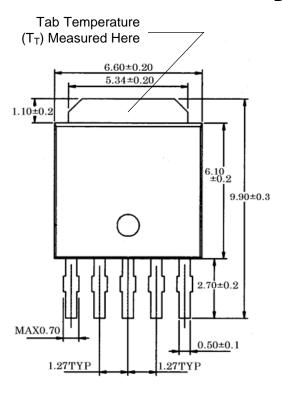
$$(V_{J} - V_{D}) \text{ and}$$

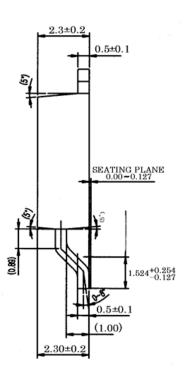
where
$$P_D = I_O \times (V_I - V_O)$$
 and $R_{\theta JT} = 6^{\circ} C/W$.

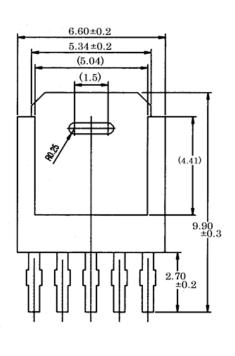




Dimensions in Millimeters







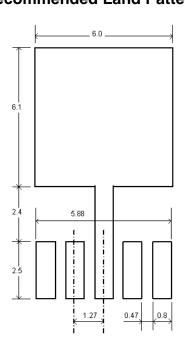
Recommended Land Pattern



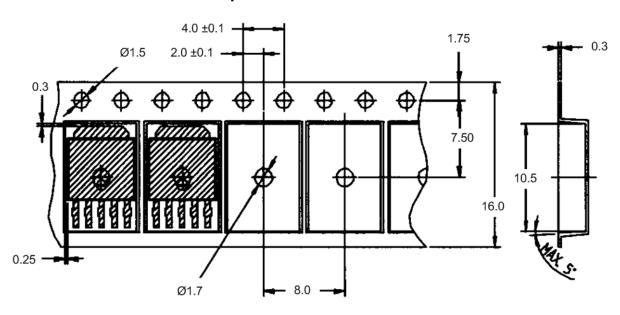
Terminal Finish: Pure Sn (category e3)

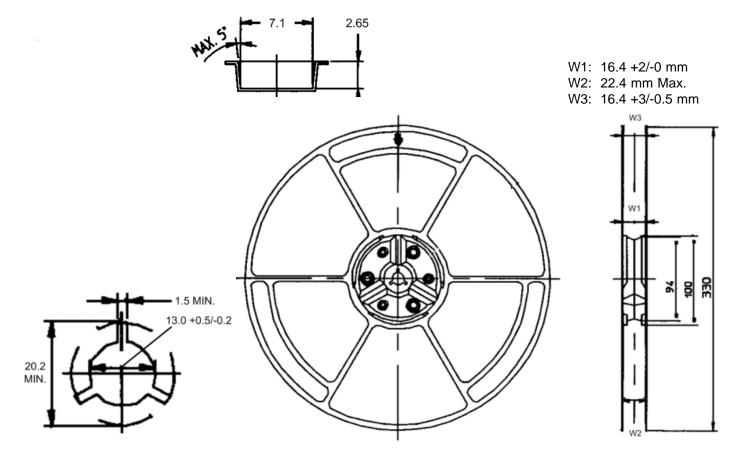
Product Weight: Approx. 0.33 g

3000 pieces per reel.



Tape and Reel Dimensions in Millimeters







Linear Regulators

SI-3025KM 1 A, Low-Dropout, 2.5 V Regulator

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